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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO		
10/747,600	12/29/2003	Hyuk Park	20063/OG03-037	6482		
34431	7590 08/27/2004		EXAM	EXAMINER		
GROSSMAN & FLIGHT, LLC			VU, D	VU, DAVID		
20 N. WACK SUITE 4220	ER DRIVE		ART UNIT	PAPER NUMBER		
CHICAGO, I	L 60606		2818			

DATE MAILED: 08/27/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applic	cation No.	Applicant(s)				
Office Action Summary		10/74	7,600	PARK ET AL.				
		Exami	iner	Art Unit	240			
		DAVID	) VU	2818	-			
Period f	The MAILING DATE of this communor Reply	nication appears on	the cover sheet w	vith the correspondence add	iress			
THE - External control	ORTENED STATUTORY PERIOD F MAILING DATE OF THIS COMMUN unsions of time may be available under the provisions SIX (6) MONTHS from the mailing date of this comic e period for reply specified above, the maximum si ure to reply within the set or extended period for reply reply received by the Office later than three months led patent term adjustment. See 37 CFR 1.704(b).	ICATION. s of 37 CFR 1.136(a). In n nunication. 30) days, a reply within the tatutory period will apply ai v will, by statute, cause the	o event, however, may a statutory minimum of thind will expire SIX (6) MO exapplication to become A	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this col. BANDONED (35 U.S.C. § 133).				
Status								
1)⊠	Responsive to communication(s) file	ed on 29 Decembe	er 2003.					
·	☐ This action is <b>FINAL</b> . 2b)☑ This action is non-final.							
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposit	ion of Claims							
5)□ 6)⊠ 7)⊠	Claim(s) 1-8 is/are pending in the application.  4a) Of the above claim(s) is/are withdrawn from consideration.  Claim(s) is/are allowed.  Claim(s) 1,2 and 4-6 is/are rejected.  Claim(s) 3,7 and 8 is/are objected to.  Claim(s) are subject to restriction and/or election requirement.							
Applicat	ion Papers							
10)⊠	The specification is objected to by the The drawing(s) filed on 29 December Applicant may not request that any objected the oath or declaration is objected to the specific product of the specific pr	er 2003 is/are: a) ction to the drawing of the correction is re-	(s) be held in abeya quired if the drawing	nce. See 37 CFR 1.85(a). g(s) is objected to. See 37 CF	R 1.121(d).			
Priority	under 35 U.S.C. § 119							
12)⊠ a)	Acknowledgment is made of a claim  All b) Some * c) None of:  1. Certified copies of the priority  2. Certified copies of the priority  3. Copies of the certified copies application from the Internation	documents have led documents have led of the priority documents Bureau (PCT)	been received. been received in a uments have been Rule 17.2(a)).	Application No n received in this National S	Stage			
	ce of References Cited (PTO-892)		4) 🔲 Interview	Summary (PTO-413)				
2) 🔲 Notio 3) 🔯 Infor	ce of Draftsperson's Patent Drawing Review (F mation Disclosure Statement(s) (PTO-1449 or er No(s)/Mail Date <u>03/17/04</u> .		Paper No	(s)/Mail Date Informal Patent Application (PTO	-152)			

#### **DETAILED ACTION**

### **Drawings**

1. Figures 1a-1b should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). A proposed drawing correction or corrected drawings are required in reply to the Office action to avoid abandonment of the application. The objection to the drawings will not be held in abeyance.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

2. Claims 1, 2 and 4-6 are rejected under 35 U. S. C. 102(e) as being anticipated by Prall et al. (US Pat. 6,624,024, herein after Prall).

Regarding claims 1 and 5, Prall discloses in figs. 3-5 a method of fabricating a memory cell and a memory cell structure comprising: forming a plurality of gate areas, the gate areas

including a gate oxide 16, a floating gate 18, an insulating layer 20, and a control gate 22 (fig. 3 and col. 4, lines 56-61); forming spacers 48 on sidewalls of the gate areas to isolate and protect a gate area including a floating gate and a control gate (col. 5, lines 15-27); forming a gap filling layer 50 over a substrate including the gate area and the spacers (fig. 5 and col. 5, lines 36-40); and depositing an insulating layer 52 over the gate areas and the gap filling layer (col. 5, lines 41-43).

Regarding claims 2 and 6, Prall discloses that the spacers 48 are formed by depositing and etching a SiN layer (col. 5, lines 15-27).

Regarding claim 4, Prall discloses that the insulating layer 52 is formed of BPSG (borophosphorsilicate glass) (col. 5, lines 41-43).

### Allowable Subject Matter

3. Claims 3, 7, 8 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter:

The prior art of record does not disclose or suggest, either singularly or in combination at least the limitation of "the gap filling layer is formed of undoped polysilicon or amorphous silicon" as recited in claims 3 and 7.

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#### Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Vu whose telephone number is (571) 272-1798. The examiner can normally be reached on Monday-Friday from 8:00am to 5:00pm. If attempt to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR, Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David Vu

August 13, 2004

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